

S3D06065A/S3D06065F/S3D06065E/S3D06065G/S3D06065I
6A 650V SIC POWER SCHOTTKY RECTIFIERS

Description

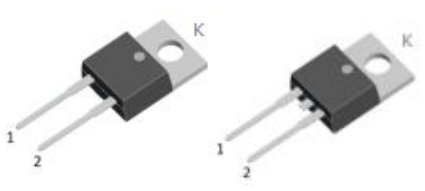
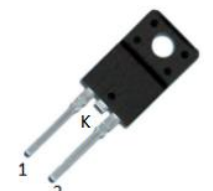
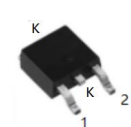
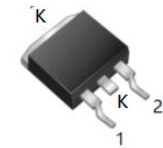


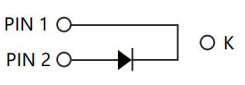
This 650V 6A diode is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D06065A/S3D06065F/S3D06065E/S3D06065G/S3D06065I are ideal for energy sensitive, high frequency applications in challenging environments.

Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- “-A” is an AEC-Q101 qualified device
- Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

<p>S3D06065A</p> 	<p>S3D06065F</p> 	<p>S3D06065E</p> 	<p>S3D06065G</p> 	<p>S3D06065I</p> 
<p>TO-220AC (TO-220-2)</p>	<p>ITO-220AC (TO-220-F2)</p>	<p>DPAK (TO-252-2)</p>	<p>D²PAK (TO-263-2)</p>	<p>TO-220-Isolation</p>
				

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	-	650	V
Average Rectified Forward Current	$I_{F(AV)1}$	$T_C=25^{\circ}C$	24	A
	$I_{F(AV)2}$	$T_C=136^{\circ}C$	9	A
	$I_{F(AV)3}$	$T_C=157^{\circ}C$	6	A
Repetitive Peak Forward Surge Current	I_{FRM1}	10ms, Half Sine pulse, $T_C=25^{\circ}C$	30	A
	I_{FRM2}	10ms, Half Sine pulse, $T_C=110^{\circ}C$	20	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM1}	10ms, Half Sine pulse, $T_C=25^{\circ}C$	70	A
	I_{FSM2}	10ms, Half Sine pulse, $T_C=110^{\circ}C$	48	A
Non-Repetitive Peak Forward Surge Current	$I_{F,Max1}$	10 μ s. Pulse, $T_C=25^{\circ}C$	600	A
	$I_{F,Max2}$	10 μ s. Pulse, $T_C=110^{\circ}C$	500	A
Power Dissipation	P_{tot1}	$T_C=25^{\circ}C$	103	W
	P_{tot2}	$T_C=110^{\circ}C$	45	W
TO-220 Mounting Torque		M3 Screw	1	Nm
		6-32 Screw	8.8	bf-in



S3D06065A
 S3D06065F
 S3D06065E
 S3D06065G
 S3D06065I

Technical Data
 Data Sheet N2331, REV.F



Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 6A, Pulse, T _J = 25 °C	1.5	1.7	V
	V _{F2}	@ 6A, Pulse, T _J = 175 °C	1.9	2.4	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.03	3	uA
	I _{R2}	@V _R = rated V _R T _J = 175 °C	0.6	25	uA
Junction Capacitance	C _T	V _R =0V, T _J =25°C, f=1MHz	382	-	pF
Reverse Recovery Charge	Q _c	I _F = 6A, di/dt = 200A/μs V _R = 400 V, T _J =25°C	23.8	-	nC
Capacitance Stored Energy	E _c	V _R = 400 V, T _J =25°C	5.88	-	μJ

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	S3D06065A	S3D06065F	S3D06065E	S3D06065G	S3D06065I	Units
Junction Temperature	T _J	-55 to +175					°C
Storage Temperature	T _{stg}	-55 to +175					°C
Typical Thermal Resistance Junction to Case	R _{θJC}	1.7	4	1.5	1.65	3.3	°C/W

Ordering Information

Device	Package	Shipping
S3D06065A	TO-220AC(TO-220-2)	50pcs / tube
S3D06065F	ITO-220AC(TO-220-F2)	50pcs / tube
S3D06065E	DPAK(TO-252-2)	2500pcs / reel
S3D06065ETR	DPAK(TO-252-2)	2500pcs / reel
S3D06065G	D2PAK(TO-263-2)	800pcs / reel
S3D06065GTR	D2PAK(TO-263-2)	800pcs / reel
S3D06065I	TO-220-Isolation	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - sales@smc-diodes.com •

Ratings and Characteristics Curves

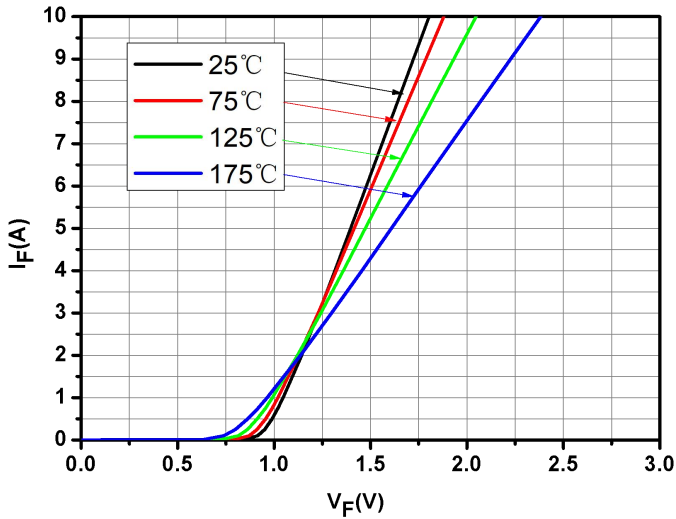


Fig.1-Typical Forward Voltage Characteristics

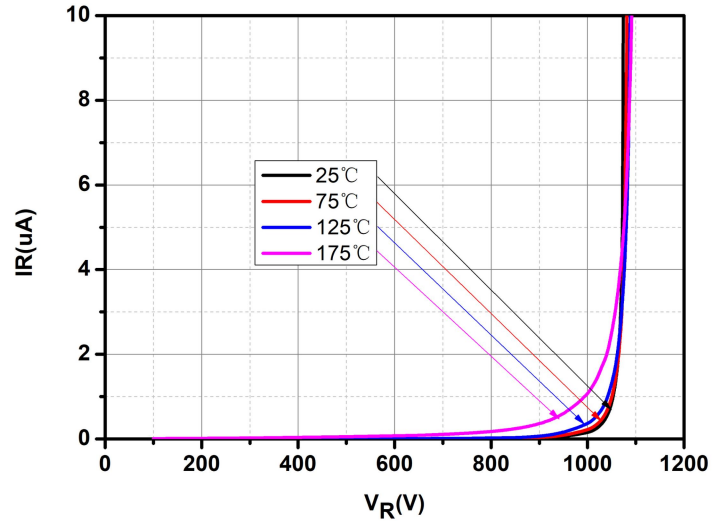


Fig.2-Typical Reverse Characteristics

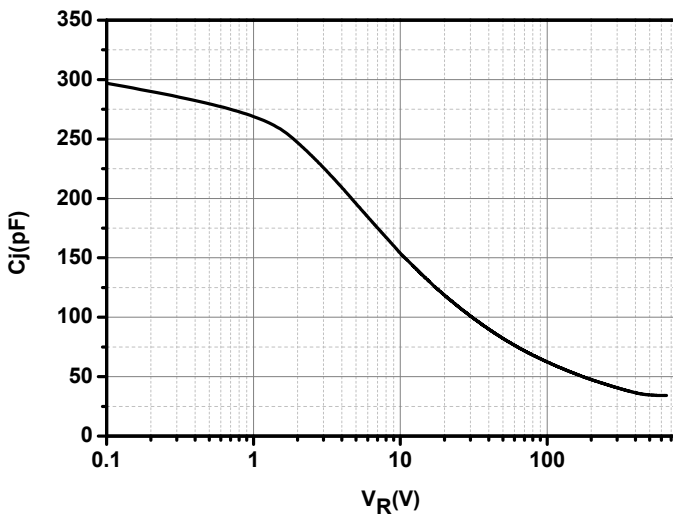


Fig.3-Capacitance vs. Reverse Voltage

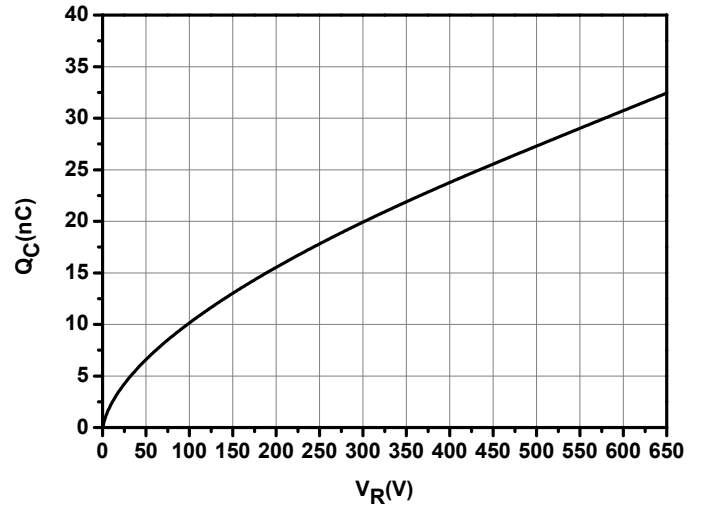


Fig.4-Total Capacitance Charge vs. Reverse Voltage

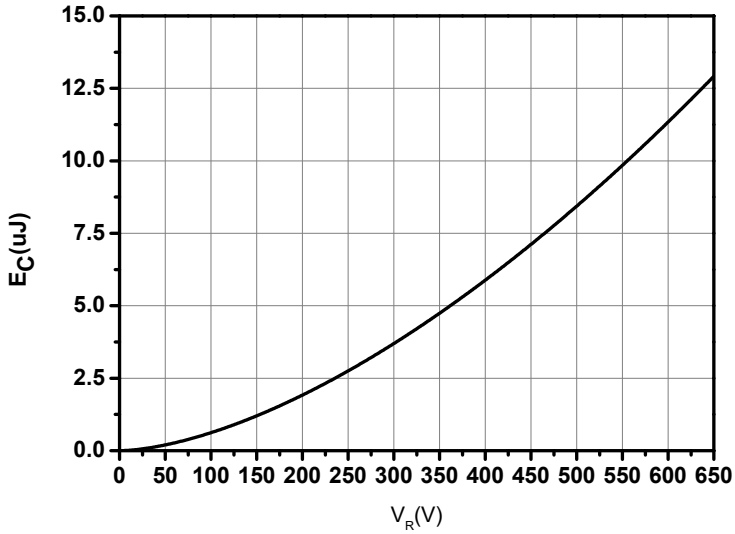


Fig.5-Capacitance Stored Energy

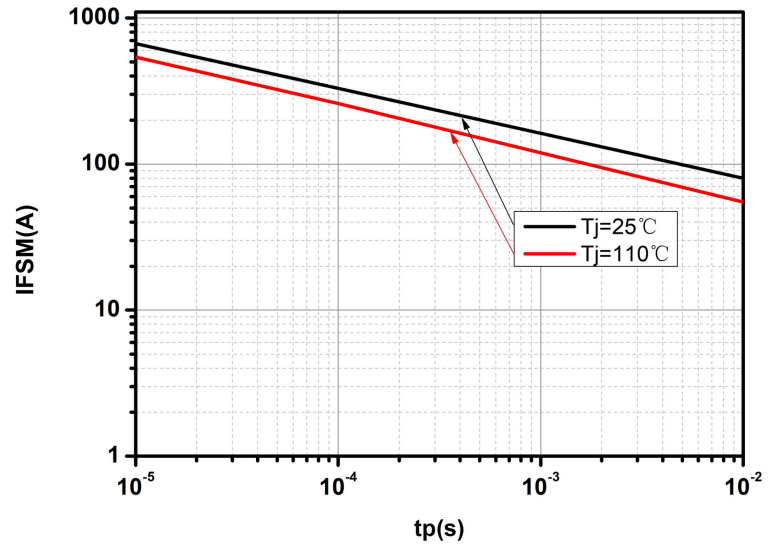


Fig.6-Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

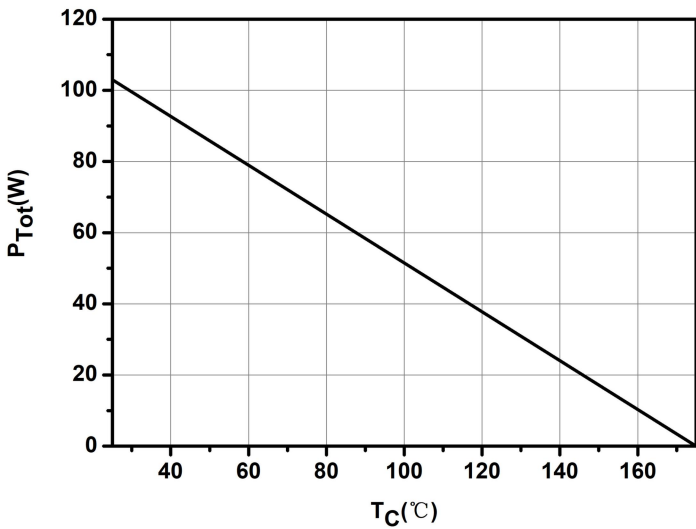


Fig.7-Power Derating

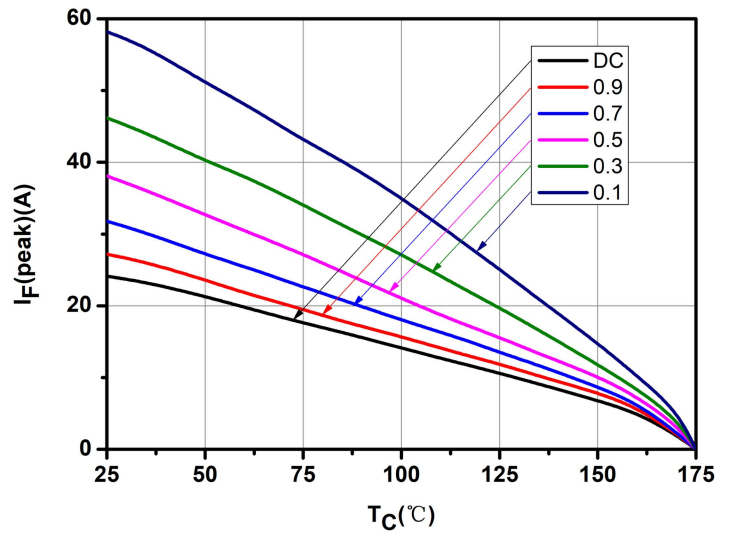
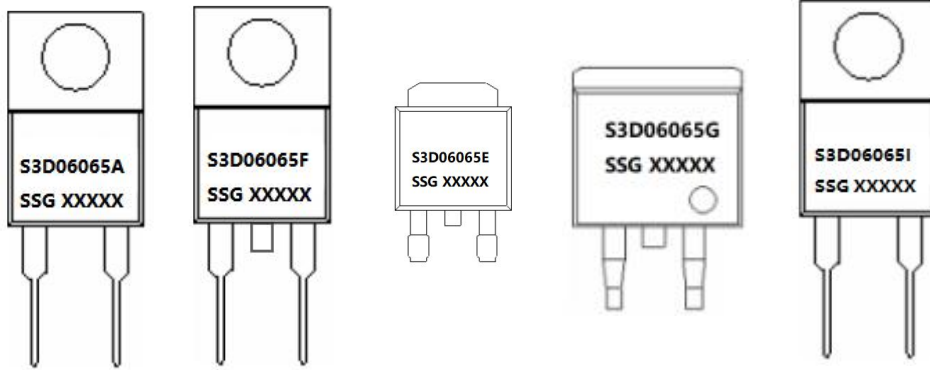


Fig.8-Current Derating

Marking Diagram

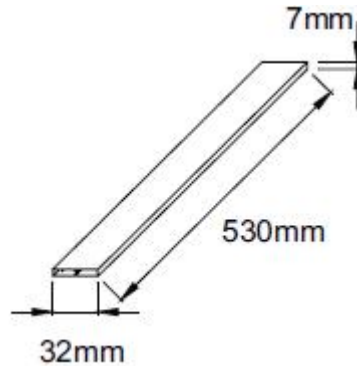


Where XXXXX is YYWWL

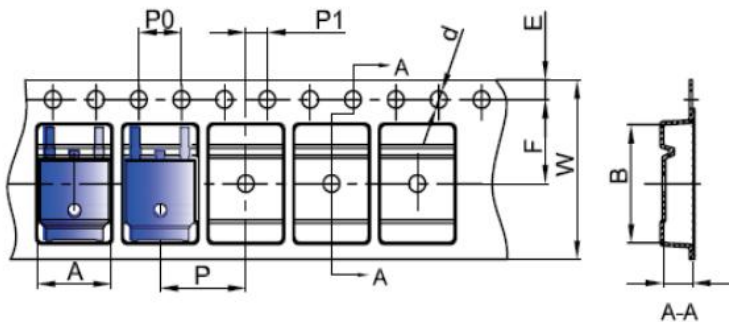
S3D = Device Type
A/F/E/G/I = Package type
06 = Forward Current (6A)
065 = Reverse Voltage (650V)
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Tube Specification(TO-220-2/TO-220-F2/TO-220-Isolation)

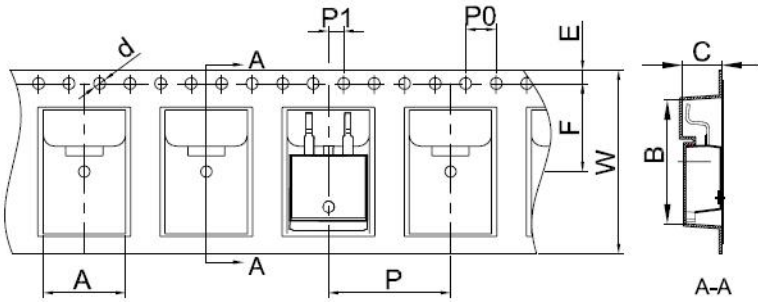


Carrier Tape & Reel Specification DPAK(TO-252-2)



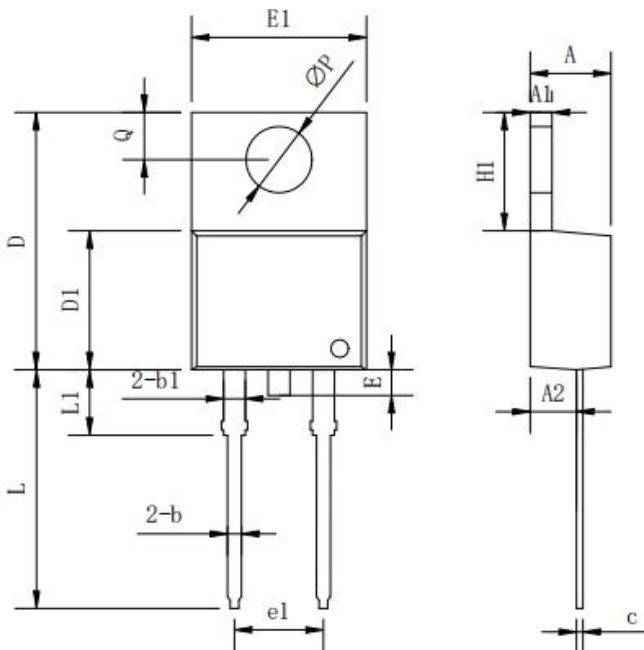
SYMBOL	Millimeters	
	Min.	Max.
A	6.80	7.00
B	10.40	10.60
C	2.60	2.80
d	Φ1.45	Φ1.65
E	1.65	1.85
F	7.40	7.60
P0	3.90	4.10
P	7.90	8.10
P1	1.90	2.10
W	15.90	16.30

Carrier Tape & Reel Specification D2PAK(TO-263-2)



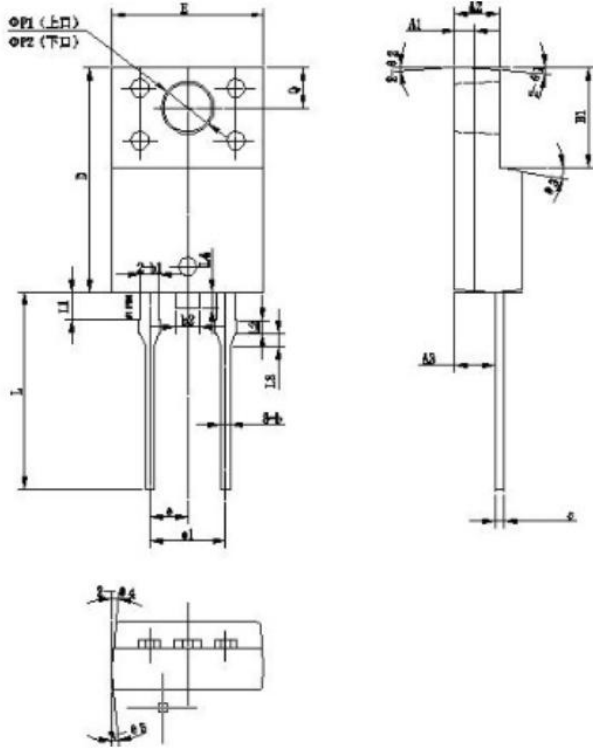
SYMBOL	Millimeters	
	Min.	Max.
A	10.70	10.90
B	16.03	16.23
C	5.11	5.31
d	1.45	1.65
E	1.65	1.85
F	11.40	11.60
P0	3.90	4.10
P	15.90	16.10
P1	1.90	2.10
W	23.90	24.30

Mechanical Dimensions TO-220AC(TO-220-2)



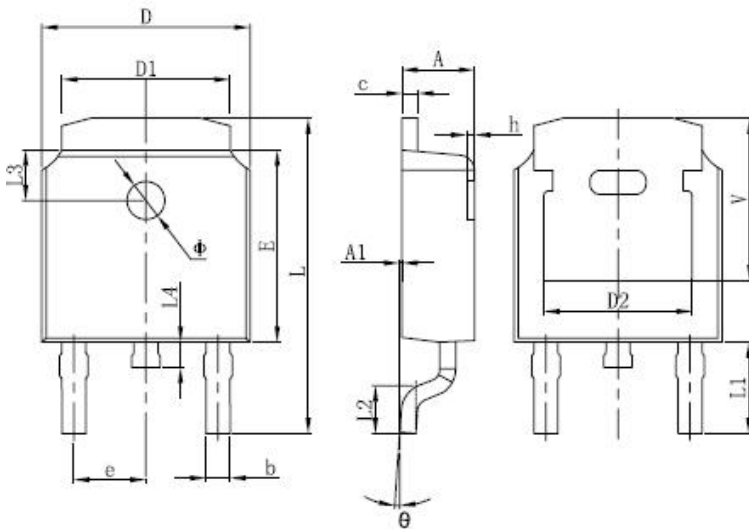
Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	3.56	-	4.83
A1	0.51	-	1.40
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
c	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	-	-	1.78
E1	9.65	10.16	10.67
e1	-	5.08	-
H1	5.84	-	6.86
L	12.70	-	14.73
L1	-	-	6.35
ØP	-	3.56	-

Mechanical Dimensions ITO-220AC(TO-220-2F)



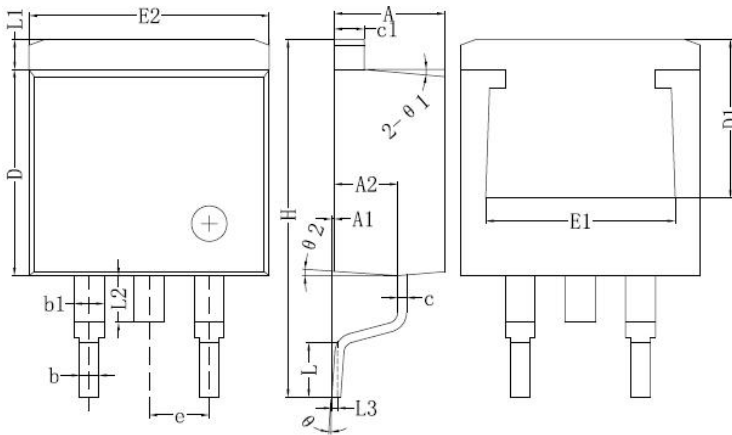
Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	4.30	4.0	4.70
A1		1.30	
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.5	0.6	0.75
b1		1.20	
b2		1.60	
e	0.55	0.6	0.75
D	14.80	15.00	15.20
E	8.96	10.14	10.36
e1		2.55	
e1		5.10	
H1	8.50	8.70	8.90
L	17.70	18.20	18.70
L1		1.80	
L2		1.00	
L3		0.80	
L4		1.10	
$\Phi P1$ (上口)	3.30	3.50	3.70
$\Phi P1$ (下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
$\Theta 1$		5°	
$\Theta 2$		4°	
$\Theta 3$		10°	
$\Theta 4$		5°	
$\Theta 5$		5°	

Mechanical Dimensions DPAK(TO-252-2)



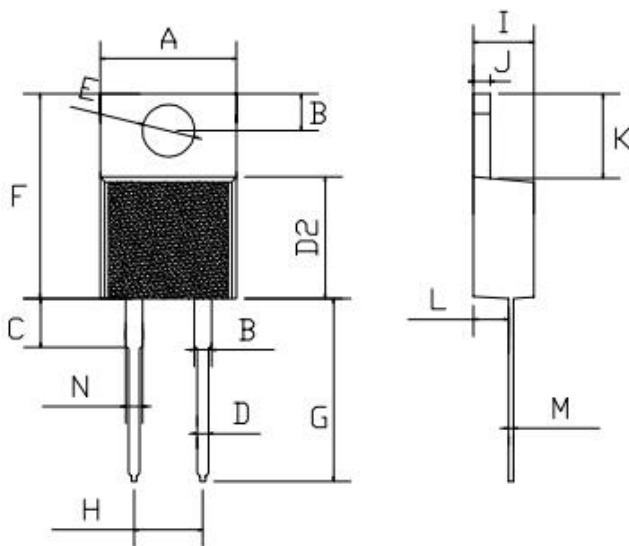
SYMBOL	Dimensions in millimeters		
	Min.	Typ.	Max.
A	2.18	-	2.39
A1	-	-	0.13
b	0.64	-	0.89
c	0.46	-	0.89
D	6.35	-	6.73
D1	4.95	-	5.46
D2	4.32	-	-
E	5.97	6.1	6.22
e		2.29BSC	
L	9.4	-	10.41
L1		2.90 REF.	
L2	1.4	1.52	1.78
L3		1.60 REF.	
L4	-	-	1.02
Φ	1.1	-	1.3
Θ	0°	-	10°
V	5.21	-	-

Mechanical Dimensions D²PAK(TO-263-2)



Symbol	Dimensions in millimeters	
	Min.	Max.
A	4.06	4.83
A1	0	0.26
b	0.51	0.99
b1	1.14	1.78
c	0.31	0.74
c1	1.14	1.65
D	8.38	9.65
D1	6.40	
E1	6.22	
E2	9.65	10.67
e	2.54BSC	
H	14.6	15.88
L	1.78	2.8
L1	-	1.68
L2	-	2.2
L3	0.255BSC	
θ	0	8°

Mechanical Dimensions TO-220-Isolation



SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	9.7	10.4	0.381	0.409
B	2.5	3.0	0.098	0.118
C	3.5	3.9	0.137	0.153
D	0.7	0.92	0.027	0.036
E	3.72	3.95	0.146	0.155
F	14.51	15.55	0.571	0.612
G	12.95	13.9	0.509	0.547
H	4.95	5.19	0.194	0.204
I	4.38	4.65	0.172	0.183
J	1.15	1.36	0.045	0.053
K	5.86	6.38	0.230	0.251
L	2.35	2.85	0.092	0.112
M	0.32	0.58	0.012	0.022
N	1.18	1.42	0.046	0.055



S3D06065A
S3D06065F
S3D06065E
S3D06065G
S3D06065I

Technical Data
Data Sheet N2331, REV.F



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